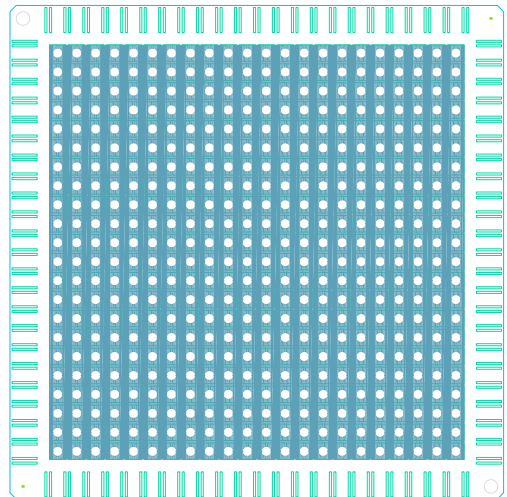


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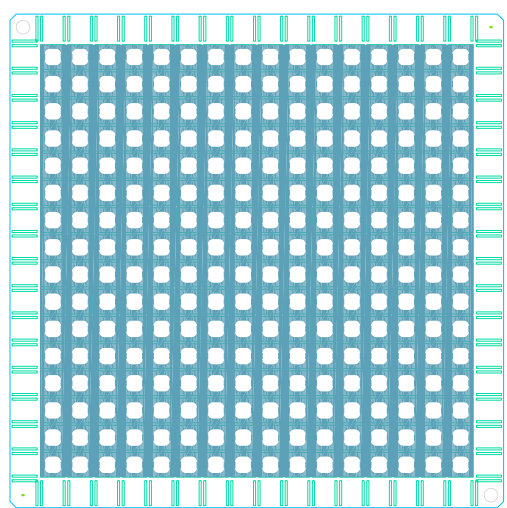
DESCRIPTION

DATE

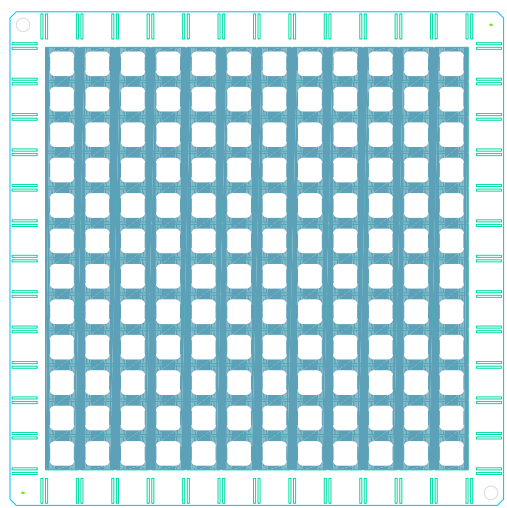
APPROVAL



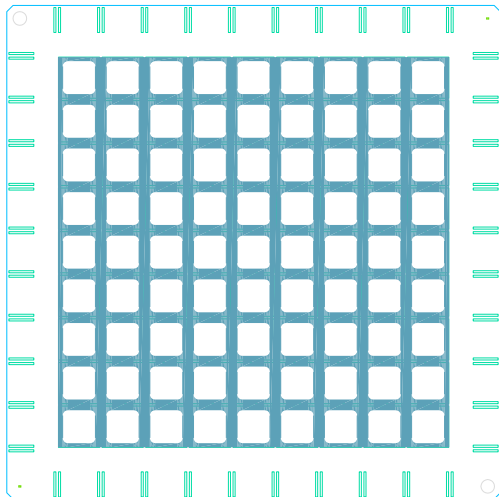
QFN D/E = 2mm
SEE DRAWING 400062



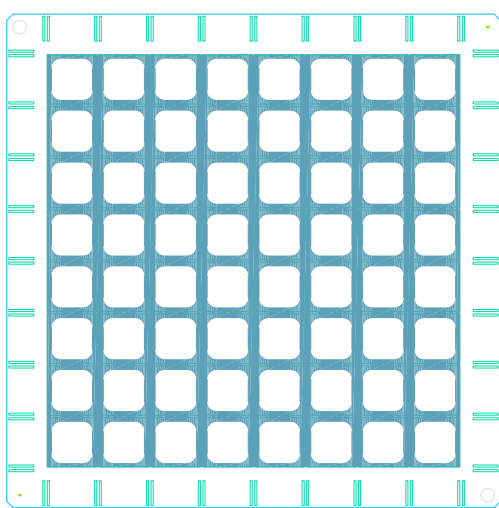
QFN D/E = 3mm
SEE DRAWING 400063



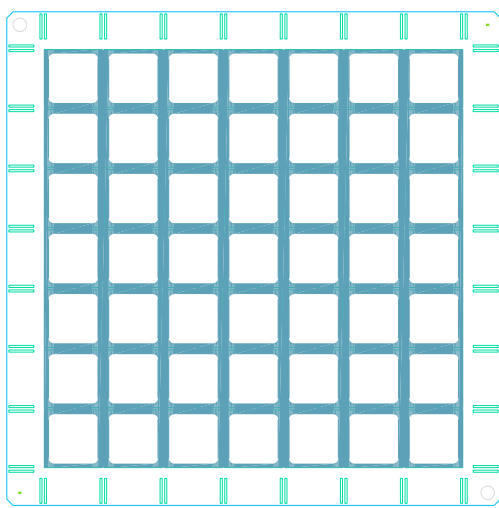
QFN D/E = 4mm
SEE DRAWING 400064



QFN D/E = 5mm
SEE DRAWING 400065



QFN D/E = 6mm
SEE DRAWING 400066



QFN D/E = 7mm
SEE DRAWING 400067

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TOLERANCES UNLESS NOTED:		APPROVALS		DATE		TITLE			
X.XX	±	DRAWN	TA	11/06/08	60X60MM QFN ARRAY				
X.XXX	±	ENG			Dam Encapsulation				
X.XXXX	±	MFG			Mirror Semiconductor™				
ANGLES ±		QA			SCALE	SIZE	DRAWING NO.	REV	
ALL DIMENSIONS ARE IN:		CUST			NONE	A	400081	A	
<input type="checkbox"/> INCHES		REVISED			DO NOT SCALE DRAWING		SHEET	1 OF 2	
<input checked="" type="checkbox"/> MILLIMETERS									

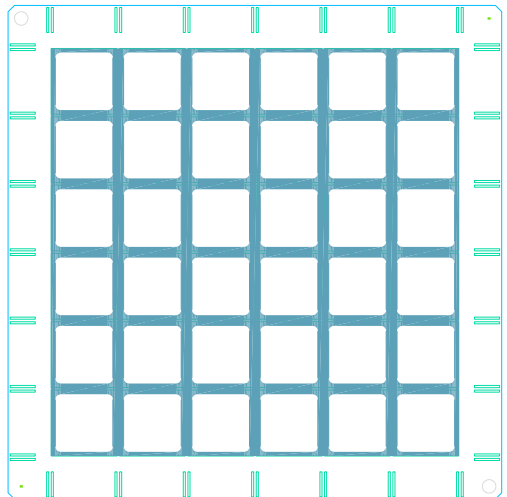


REV

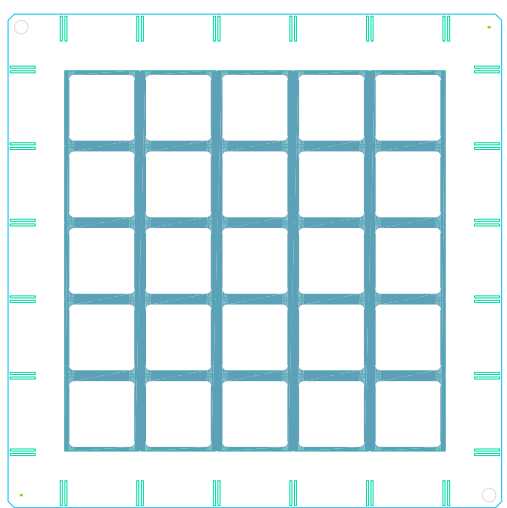
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DATE

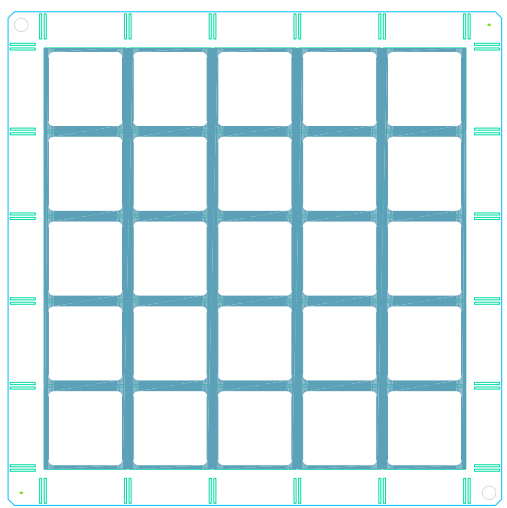
APPROVAL



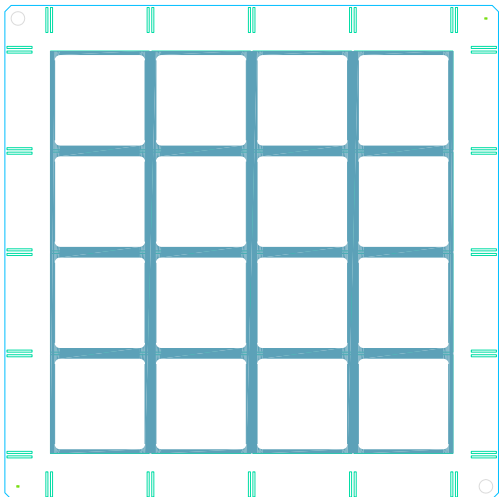
QFN D/E = 8mm
SEE DRAWING 400068



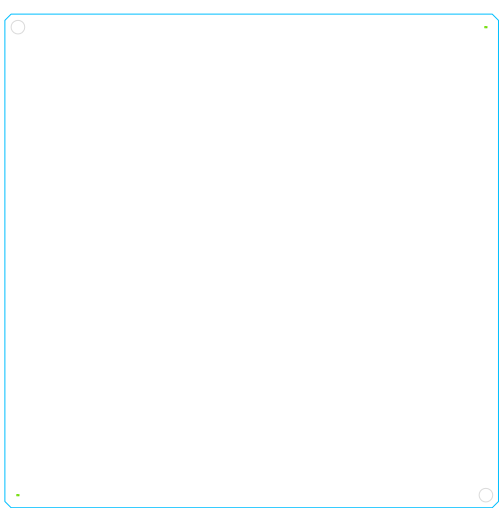
QFN D/E = 9mm
SEE DRAWING 400069





QFN D/E = 10mm
SEE DRAWING 400070



QFN D/E = 12mm
SEE DRAWING 400072



OUTLINE 60X60mm

TOLERANCES UNLESS NOTED:		APPROVALS		DATE		 Mirror TM Semiconductor Darn Encapsulation 60X60MM QFN ARRAY				
X.XX	±	DRWN	TA	11/06/08	TITLE					SCALE
X.XXX	±	ENG			60X60MM QFN ARRAY		NONE	A	400081	A
X.XXXX	±	MFG			Darn Encapsulation					
ANGLES	±	QA			DO NOT SCALE DRAWING					
ALL DIMENSIONS ARE IN:		REVISED		SHEET		2 OF 2				
<input type="checkbox"/> INCHES										
<input checked="" type="checkbox"/> MILLIMETERS										
THIRD ANGLE PROJECTION:										
										

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